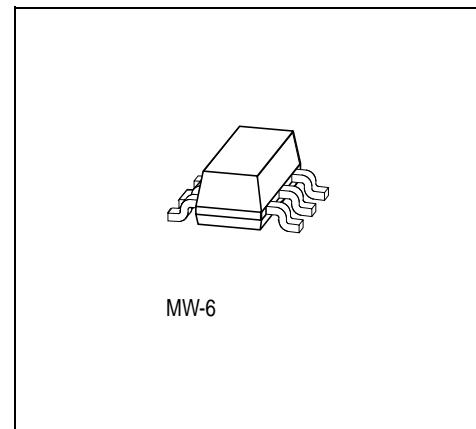


# GaAs MMIC

## Data Sheet

**CGY 60**

- Low noise preamplifier for mobile communication (PCN, DECT, GSM) in 2.7 V to 6 V systems
- Biased monolithic microwave IC (MMIC) matched to 50 W for 1.7 to 2 GHz
- Easily matchable to 50  $\Omega$  for lower frequencies (i.e. GSM-application)
- No bias coil needed
- Low noise figure and high gain (typ. NF = 1.9 dB,  $G = 12.5$  dB @ 3 V, 1.85 GHz)
- Low power consumption
- Frequency range 200 MHz ... 2.5 GHz



**ESD:** Electrostatic discharge sensitive device,  
observe handling precautions!

Type	Marking	Ordering Code (taped)	Package <sup>1)</sup>
CGY 60	Y7s	Q62702-G39	MW-6

<sup>1)</sup> Dimensions see **Page 10**.

Maximum Ratings	Symbol	Value	Unit
Drain voltage	$V_D$	8	V
Channel temperature	$T_{Ch}$	150	°C
Storage temperature range	$T_{stg}$	- 55 ... + 150	°C
Total power dissipation ( $T_S \leq 132$ °C) <sup>1)</sup>	$P_{tot}$	80	mW

<sup>1)</sup> Please care for sufficient heat dissipation on the pcb!

Thermal Resistance	Symbol	Value	Unit
Channel-soldering point (GND)	$R_{thChS}$	$\leq 220$	K/W
Channel-ambient <sup>1)</sup>	$R_{thChA}$	< 300	K/W

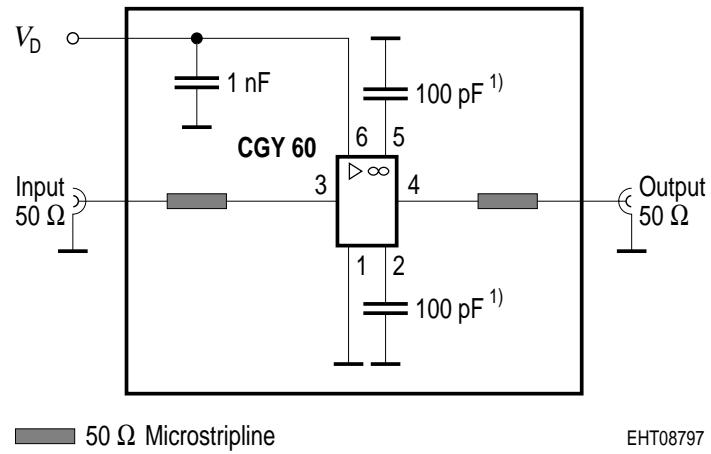
<sup>1)</sup> Package mounted on alumina 15 mm × 16.7 mm × 0.7 mm.

**Electrical Characteristics of CGY 60 in GSM Application Circuit**
 $T_A = 25^\circ\text{C}$ ,  $f = 950 \text{ MHz}$ ,  $R_S = R_L = 50 \Omega$ , unless otherwise specified.

<b>Characteristics</b>	<b>Symbol</b>	<b>Limit Values</b>			<b>Unit</b>
		<b>min.</b>	<b>typ.</b>	<b>max.</b>	
Drain current $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$I_D$	—	6	9	mA
Power Gain $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$G$	—	15.5	—	dB
Noise figure $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$F$	—	1.35	—	dB
Input return loss $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$RL_{in}$	—	10	—	dB
Output return loss $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$RL_{out}$	—	11	—	dB
Third order input intercept point two-tone intermodulation test $f_1 = 950 \text{ MHz}$ , $f_2 = 951 \text{ MHz}$ $P_{in} = -20 \text{ dBm}$ (both carriers) $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$IP_3$	—	—	—	dBm
Input power at 1 dB gain compression $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$P_{-1 \text{ dB}}$	—	—	—	dBm

**Electrical Characteristics in PCN-, DECT-Application Circuit**
 $T_A = 25^\circ\text{C}$ ,  $f = 1850 \text{ MHz}$ ,  $R_S = R_L = 50 \Omega$ , unless otherwise specified.

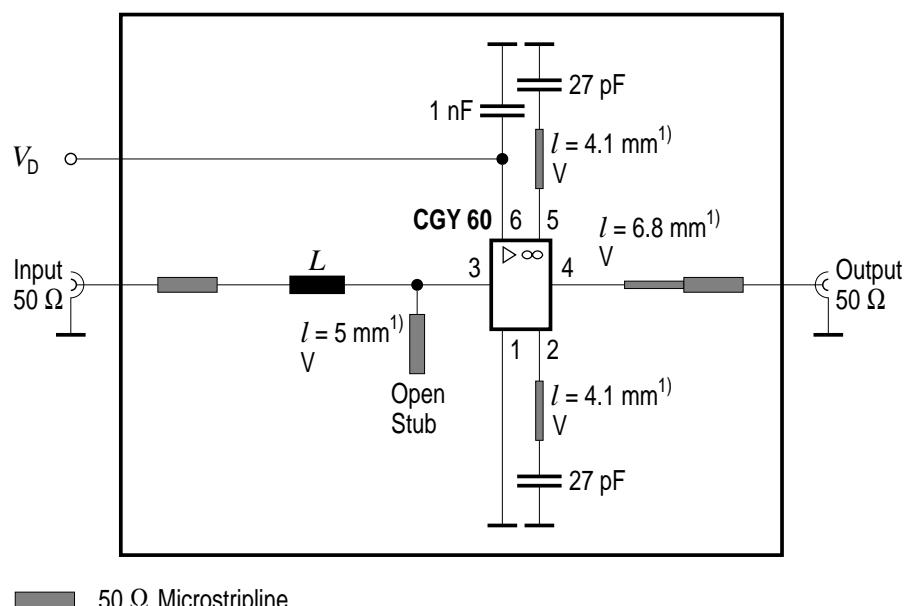
<b>Characteristics</b>	<b>Symbol</b>	<b>Limit Values</b>			<b>Unit</b>
		<b>min.</b>	<b>typ.</b>	<b>max.</b>	
Drain current $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$I_D$	—	6	9	mA
Power Gain $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$G$	—	12.5 13.5	— —	dB
Noise figure $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$F$	—	1.90 1.85	— —	dB
Input return loss $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$RL_{in}$	—	14.5 14.5	— —	dB
Output return loss $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$RL_{out}$	—	14 14	— —	dB
Third order input intercept point two-tone intermodulation test $f_1 = 1850 \text{ MHz}$ , $f_2 = 1851 \text{ MHz}$ $P_{in} = -20 \text{ dBm}$ (both carriers) $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$IP_3$	—	0 2	— —	dBm
Input power at 1 dB gain compression $U_d = 3 \text{ V}$ $U_d = 5 \text{ V}$	$P_{-1 \text{ dB}}$	—	-7 -5	— —	dBm



EHT08797

**Figure 1 Application Circuit for Measuring S- and Noise-Parameters**  
 $f = 200 \text{ MHz to } 2 \text{ GHz}$

<sup>1)</sup> Use 12 to 15 pF for DECT - or PCN - applications.



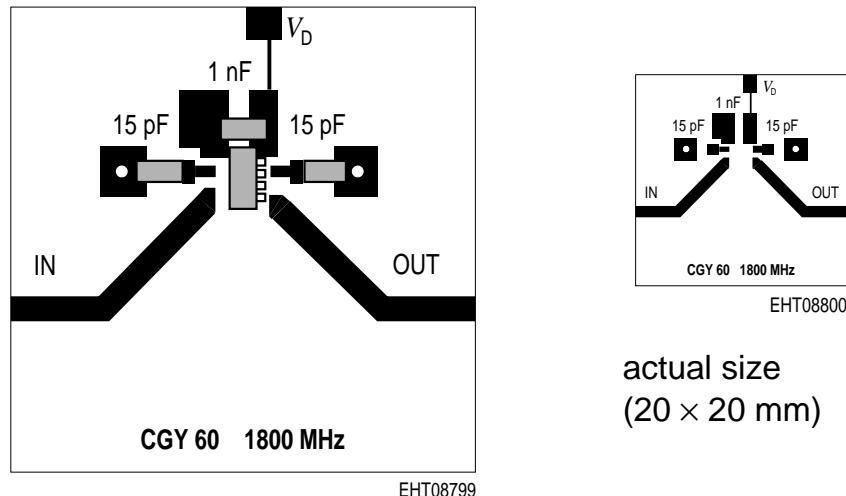
L: Discrete inductor 15 nH, type SIMID01, Ord. No: B82412-A3150-M

$$V = \frac{1}{\sqrt{\epsilon_{\text{refl}}}}$$

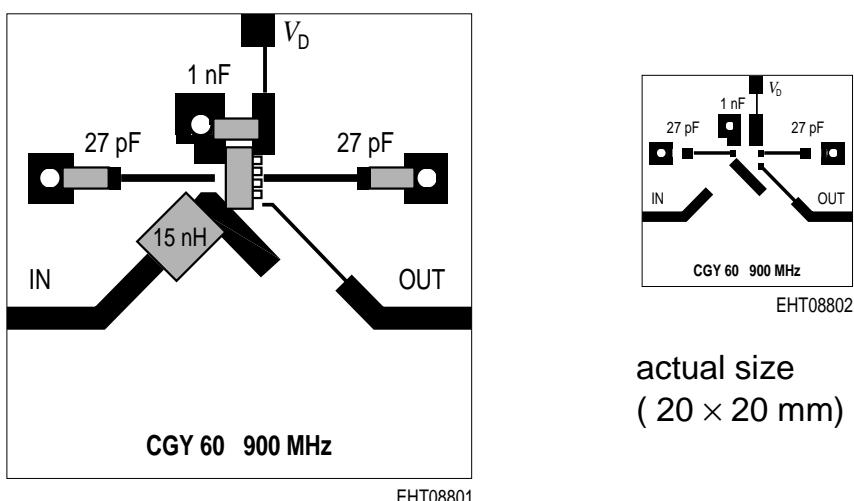
EHT08798

**Figure 2 900 MHz Application (GSM)**

## PCB - Layouts for Application Circuits



**Figure 3** PCN -, DECT - Application Board



**Figure 4** GSM - Application Board

PCB - data: Glass fiber teflon board (double sided) TACONIC TLX-9-0150-CH/CH.

$\epsilon_r = 2.45$ , thickness = 0.4 mm

**Typical S- and Noise-Parameters**
 $V_D = 3 \text{ V}$ ,  $Z_o = 50 \Omega$ 

<b><i>f</i></b>	<b>S11</b>		<b>S21</b>		<b>S12</b>		<b>S22</b>	
	<b>GHZ</b>	<b>MAG</b>	<b>ANG</b>	<b>MAG</b>	<b>ANG</b>	<b>MAG</b>	<b>ANG</b>	<b>MAG</b>
0.1	0.97	- 5	2.98	- 135	0.005	80	0.74	- 34
0.2	0.97	- 9	3.85	- 162	0.009	77	0.51	- 44
0.3	0.96	- 14	4.13	- 177	0.013	74	0.41	- 47
0.4	0.94	- 19	4.27	172	0.017	73	0.35	- 48
0.5	0.93	- 23	4.35	163	0.021	71	0.33	- 49
0.6	0.91	- 29	4.40	155	0.026	67	0.31	- 51
0.7	0.88	- 34	4.45	148	0.029	65	0.30	- 54
0.8	0.85	- 40	4.48	140	0.033	63	0.29	- 58
0.9	0.81	- 46	4.51	132	0.037	60	0.29	- 63
1.0	0.76	- 52	4.55	125	0.042	54	0.28	- 69
1.1	0.71	- 59	4.60	117	0.045	50	0.27	- 74
1.2	0.64	- 66	4.62	110	0.048	46	0.26	- 80
1.3	0.58	- 74	4.63	102	0.051	41	0.26	- 86
1.4	0.51	- 83	4.61	94	0.053	36	0.25	- 93
1.5	0.43	- 93	4.58	85	0.054	31	0.24	- 101
1.6	0.34	- 106	4.51	77	0.055	26	0.23	- 109
1.7	0.26	- 122	4.40	69	0.055	20	0.22	- 118
1.8	0.19	- 149	4.30	60	0.054	15	0.21	- 128
1.9	0.15	172	4.13	51	0.051	11	0.20	- 140
2.0	0.18	131	3.94	43	0.049	5	0.19	- 151
2.1	0.24	106	3.73	35	0.046	2.5	0.18	- 163
2.2	0.32	90	3.56	27	0.043	- 5	0.18	177
2.3	0.39	78	3.33	20	0.038	- 9	0.18	170
2.4	0.46	69	3.09	13	0.033	- 11	0.18	160
2.5	0.52	61	2.87	5	0.028	- 12	0.19	151

<b><i>f</i></b>	<b><i>F</i><sub>min</sub></b>	<b><math>\Gamma_{\text{opt}}</math></b>		<b><i>R<sub>N</sub></i></b>
		<b>MAG</b>	<b>ANG</b>	
<b>GHz</b>	<b>dB</b>	<b>-</b>	<b>deg</b>	<b><math>\Omega</math></b>
0.9	1.27	0.70	27	47.8
1.3	1.35	0.63	39	32.7
1.8	1.50	0.42	59	18.2
2.0	1.60	0.30	62	15.0

### Typical S- and Noise-Parameters

$V_D = 3 \text{ V}$ ,  $Z_0 = 50 \Omega$

<b><i>f</i></b>	<b>S11</b>		<b>S21</b>		<b>S12</b>		<b>S22</b>	
<b>GHZ</b>	<b>MAG</b>	<b>ANG</b>	<b>MAG</b>	<b>ANG</b>	<b>MAG</b>	<b>ANG</b>	<b>MAG</b>	<b>ANG</b>
0.1	0.97	− 4	3.58	− 137	0.005	74	0.72	− 31
0.2	0.97	− 9	4.49	− 164	0.009	75	0.52	− 37
0.3	0.96	− 14	4.78	− 178	0.013	74	0.44	− 38
0.4	0.94	− 18	4.91	171	0.017	71	0.39	− 39
0.5	0.93	− 23	4.96	163	0.021	70	0.37	− 40
0.6	0.90	− 28	5.02	154	0.024	67	0.36	− 42
0.7	0.88	− 34	5.09	147	0.028	64	0.35	− 45
0.8	0.85	− 39	5.11	139	0.032	62	0.34	− 50
0.9	0.81	− 45	5.14	132	0.036	60	0.34	− 54
1.0	0.76	− 51	5.16	125	0.041	55	0.33	− 59
1.1	0.71	− 58	5.23	118	0.044	50	0.32	− 64
1.2	0.65	− 65	5.25	110	0.046	45	0.31	− 70
1.3	0.59	− 72	5.25	102	0.049	42	0.30	− 75
1.4	0.52	− 81	5.25	95	0.050	37	0.29	− 81
1.5	0.44	− 90	5.21	87	0.052	32	0.27	− 88
1.6	0.36	− 103	5.15	78	0.052	27	0.26	− 95
1.7	0.28	− 118	5.05	70	0.052	23	0.24	− 102

**Typical S- and Noise-Parameters (cont'd)**
 $V_D = 3 \text{ V}$ ,  $Z_o = 50 \Omega$ 

<b><i>f</i></b>	<b>S11</b>		<b>S21</b>		<b>S12</b>		<b>S22</b>	
<b>GHZ</b>	<b>MAG</b>	<b>ANG</b>	<b>MAG</b>	<b>ANG</b>	<b>MAG</b>	<b>ANG</b>	<b>MAG</b>	<b>ANG</b>
1.8	0.20	- 140	4.93	62	0.051	17	0.22	- 111
1.9	0.16	- 176	4.77	53	0.050	13	0.20	- 121
2.0	0.17	141	4.57	45	0.047	8	0.18	- 131
2.1	0.23	113	4.36	37	0.045	5	0.17	- 142
2.2	0.31	95	4.18	29	0.042	- 2	0.16	- 158
2.3	0.38	82	3.92	21	0.037	- 6	0.14	- 173
2.4	0.45	72	3.66	14	0.032	- 8	0.14	174
2.5	0.52	64	3.39	7	0.027	- 9	0.14	162

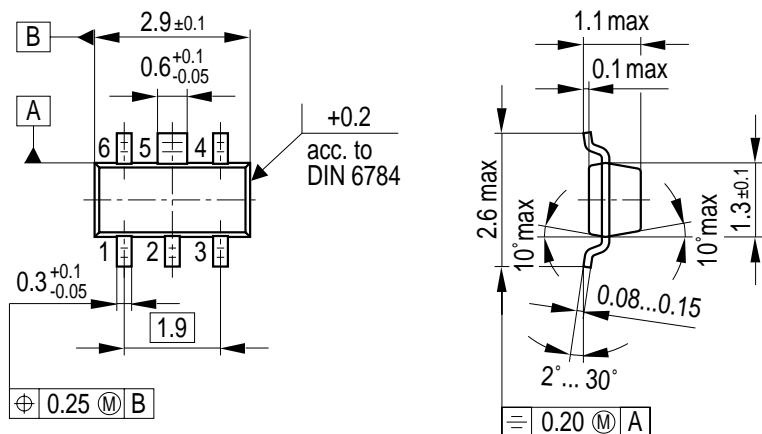
<b><i>f</i></b>	<b><i>F</i><sub>min</sub></b>	<b><math>\Gamma_{\text{opt}}</math></b>		<b><i>R<sub>N</sub></i></b>
		<b>MAG</b>	<b>ANG</b>	
<b>GHz</b>	<b>dB</b>	<b>-</b>	<b>deg</b>	<b><math>\Omega</math></b>
0.9	1.23	0.69	26	47.7
1.3	1.32	0.67	39	33.3
1.8	1.45	0.45	55	18.6
2.0	1.53	0.32	60	15.2

<b>Dim.</b>	<b>min.</b>	<b>nom.</b>	<b>max.</b>	<b>Gradient</b>	<b>Remark</b>
A	–	–	1.1	–	–
A <sub>1</sub>	–	–	0.1	–	–
A <sub>2</sub>	–	–	1.0	–	–
b	–	0.3	–	–	–
b <sub>1</sub>	–	0.6	–	–	–
c	0.08	–	0.15	–	–
D	2.8	–	3.0	–	–
E	1.2	–	1.4	–	–
e	–	0.95	–	–	–
e <sub>1</sub>	–	1.9	–	–	–
H <sub>E</sub>	–	–	2.6	–	–
L <sub>E</sub>	–	–	0.6	–	–
a	–	–	–	max 10°	<sup>1)</sup>
q	–	–	–	2° ... 30°	–

<sup>1)</sup> Applicable on all case top sides.

## Package Outlines

### MW-6 (Special Package)



GPW05794

### Sorts of Packing

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information".

SMD = Surface Mounted Device

Dimensions in mm